

Product Specification

XBLW SN74LS365

Hex Buffer/Line Driver; 3-state

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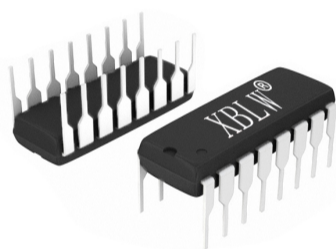


Description

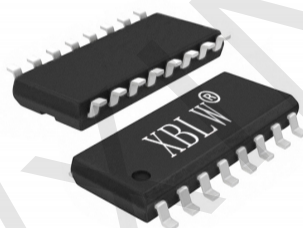
The SN74LS365 is a hex buffer/line driver with 3-state outputs controlled by the output enable inputs ($\overline{OEn}$). A HIGH on $\overline{OEn}$ causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features

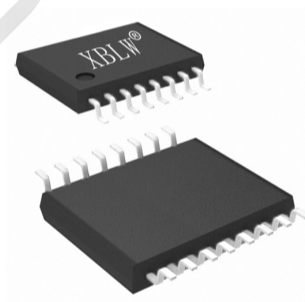
- 3-state outputs
- Specified from -20°C to +85°C
- Packaging information: DIP-16/SOP-16/TSSOP-16



DIP-16



SOP-16



TSSOP-16

Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW SN74LS365N	DIP-16	74LS365N	Tube	1000Pcs/Box
XBLW SN74LS365DTR	SOP-16	74LS365	Tape	2500Pcs/Reel
XBLW SN74LS365TDTR	TSSOP-16	74LS365	Tape	3000Pcs/Reel

Block Diagram

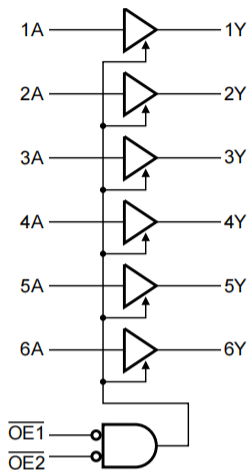


Figure 1. Logic symbol

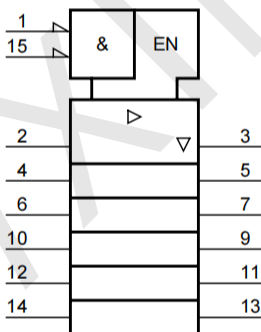


Figure 2. IEC logic symbol

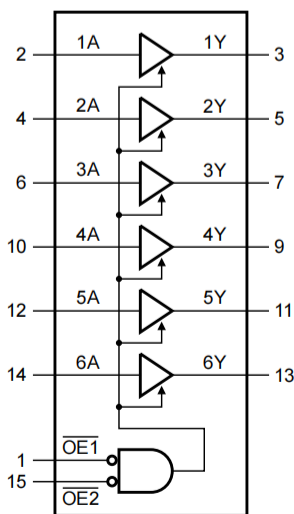


Figure 3. Functional diagram

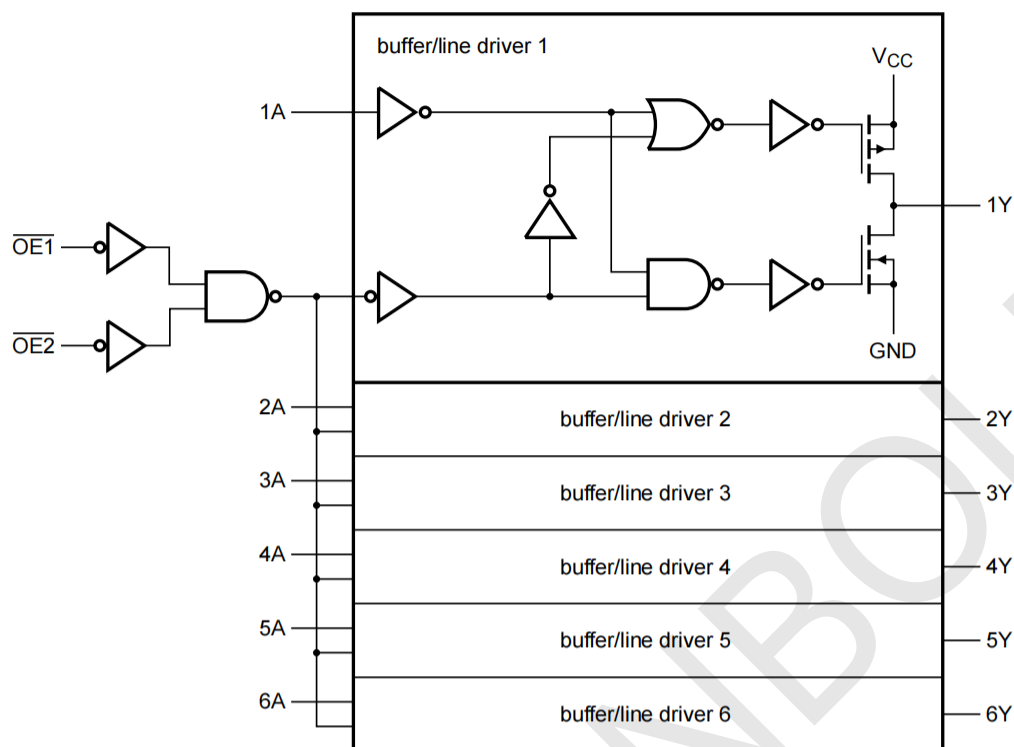
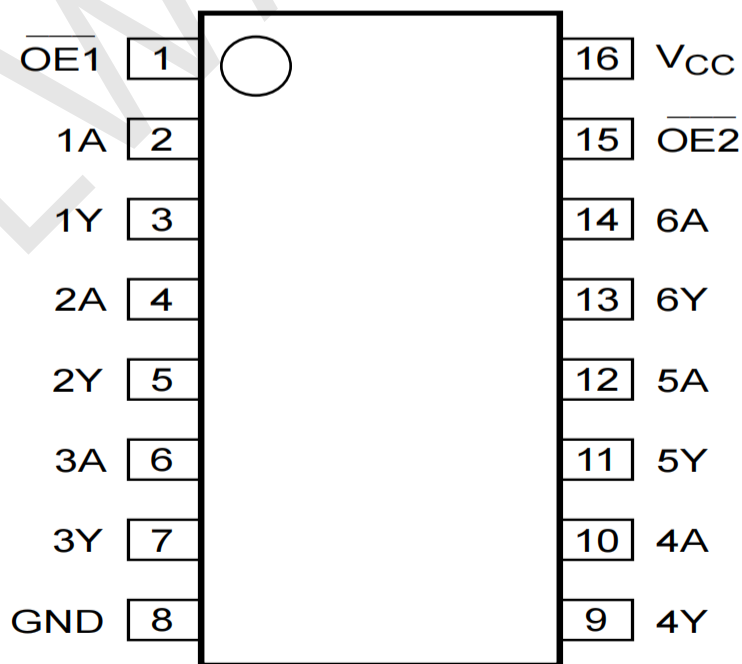


Figure 4. Logic diagram

Pin Configurations



Pin DescriptionFunction Table

Pin No.	Pin Name	Description
1	$\overline{OE}1$	output enable input 1 (active LOW)
2	1A	data input 1
3	1Y	data output 1
4	2A	data input 2
5	2Y	data output 2
6	3A	data input 3
7	3Y	data output 3
8	GND	ground (0V)
9	4Y	data output 4
10	4A	data input 4
11	5Y	data output 5
12	5A	data input 5
13	6Y	data output 6
14	6A	data input 6
15	$\overline{OE}2$	output enable input 2 (active LOW)
16	V _{CC}	supply voltage

Function Table

Input			Output
$\overline{OE}1$	$\overline{OE}2$	nA	nY
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

Note: H=HIGH voltage level; L=LOW voltage level; X=don'tcare; Z=high-impedance OFF-state.

Electrical Parameter

Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+7.0	V
input clamping current	I_{IK}	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$	-	± 20	mA
output clamping current	I_{OK}	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$	-	± 20	mA
output current	I_O	$-0.5V < V_O < V_{CC}+0.5V$	-	± 35	mA
supply current	I_{CC}	-	-	70	mA
ground current	I_{GND}	-	-70	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	500	mW
Soldering temperature	T_L	10s	DIP	245	°C
			SOP/TSSOP	260	

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	2.0	5.0	6.0	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=2.0V$	-	-	625	ns/V
		$V_{CC}=4.5V$	-	1.67	139	ns/V
		$V_{CC}=6.0V$	-	-	83	ns/V
ambient temperature	T_{amb}	-	-20	-	+85	°C

DC Characteristics 1

($T_{amb}=25^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$		1.5	1.2	-	V
		$V_{CC}=4.5\text{V}$		3.15	2.4	-	V
		$V_{CC}=6.0\text{V}$		4.2	3.2	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$		-	0.8	0.5	V
		$V_{CC}=4.5\text{V}$		-	2.1	1.35	V
		$V_{CC}=6.0\text{V}$		-	2.8	1.8	V
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O=-20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	2.0	-	V
			$I_O=-20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	4.5	-	V
			$I_O=-20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	6.0	-	V
			$I_O=-6.0\text{mA}; V_{CC}=4.5\text{V}$	3.98	4.32	-	V
			$I_O=-7.8\text{mA}; V_{CC}=6.0\text{V}$	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O=20\mu\text{A}; V_{CC}=2.0\text{V}$	-	0	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	0	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=6.0\text{V}$	-	0	0.1	V
			$I_O=6.0\text{mA}; V_{CC}=4.5\text{V}$	-	0.15	0.26	V
			$I_O=7.8\text{mA}; V_{CC}=6.0\text{V}$	-	0.16	0.26	V
input leakage current	I_I	$V_I=V_{CC} \text{ or } \text{GND}; V_{CC}=6.0\text{V}$		-	-	± 0.1	μA
OFF-state output current	I_{OZ}	$V_I=V_{IH} \text{ or } V_{IL}; V_{CC}=6.0\text{V}; V_O=V_{CC} \text{ or } \text{GND}$		-	-	± 0.5	μA
supply current	I_{CC}	$V_I=V_{CC} \text{ or } \text{GND}; I_O=0\text{A}; V_{CC}=6.0\text{V}$		-	-	8.0	μA
input capacitance	C_I	-		-	3.5	-	pF

DC Characteristics 2

($T_{amb} = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$		1.5	-	-	V
		$V_{CC}=4.5\text{V}$		3.15	-	-	V
		$V_{CC}=6.0\text{V}$		4.2	-	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$		-	-	0.5	V
		$V_{CC}=4.5\text{V}$		-	-	1.35	V
		$V_{CC}=6.0\text{V}$		-	-	1.8	V
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = -20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	-	-	V
			$I_O = -20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	-	-	V
			$I_O = -20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	-	-	V
			$I_O = -6.0\text{mA}; V_{CC}=4.5\text{V}$	3.84	-	-	V
			$I_O = -7.8\text{mA}; V_{CC}=6.0\text{V}$	5.34	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = 20\mu\text{A}; V_{CC}=2.0\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC}=4.5\text{V}$	-	-	0.1	V
			$I_O = 20\mu\text{A}; V_{CC}=6.0\text{V}$	-	-	0.1	V
			$I_O = 6.0\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.33	V
			$I_O = 7.8\text{mA}; V_{CC}=6.0\text{V}$	-	-	0.33	V
input leakage current	I_I	$V_I = V_{CC} \text{ or } \text{GND}; V_{CC}=6.0\text{V}$		-	-	± 1.0	μA
OFF-state output current	I_{OZ}	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC}=6.0\text{V}; V_O = V_{CC} \text{ or } \text{GND}$		-	-	± 5.0	μA
supply current	I_{CC}	$V_I = V_{CC} \text{ or } \text{GND}; I_O = 0\text{A}; V_{CC}=6.0\text{V}$		-	-	80	μA

AC Characteristics 1

($T_{amb}=25^{\circ}C$, $GND=0V$, $C_L=50pF$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
nA tonY propagation delay	t_{pd}	see Figure 6	$V_{CC}=2.0V$	-	30	95 ns
			$V_{CC}=4.5V$	-	11	19 ns
			$V_{CC}=5.0V$; $C_L=15pF$	-	9	- ns
			$V_{CC}=6.0V$	-	9	16 ns
$\overline{O}En$ to nY enable time	t_{en}	see Figure 7	$V_{CC}=2.0V$	-	47	150 ns
			$V_{CC}=4.5V$	-	17	30 ns
			$V_{CC}=6.0V$	-	14	26 ns
$\overline{O}En$ to nY disable time	t_{dis}	see Figure 7	$V_{CC}=2.0V$	-	61	150 ns
			$V_{CC}=4.5V$	-	22	30 ns
			$V_{CC}=6.0V$	-	18	26 ns
transition time	t_t	see Figure 6	$V_{CC}=2.0V$	-	14	60 ns
			$V_{CC}=4.5V$	-	5	12 ns
			$V_{CC}=6.0V$	-	4	10 ns
power dissipation capacitance	C_{PD}	per buffer; $V_I=GND$ to V_{CC}	-	40	-	pF

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_{en} is the same as t_{PZL} and t_{PZH} .

[3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i =input frequency in MHz;

f_o =output frequency in MHz;

C_L =output load capacitance in pF; V_{CC} =supply voltage in V;

N =number of inputs switching; $\sum (C_L \times V_{CC}^2 \times f_o)$ =sum of outputs.

AC Characteristics 2

($T_{amb} = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $GND = 0V$, $C_L = 50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
nA tonY propagation delay	t_{pd}	see Figure 6	$V_{CC} = 2.0V$	-	-	120 ns
			$V_{CC} = 4.5V$	-	-	24 ns
			$V_{CC} = 6.0V$	-	-	20 ns
$\overline{O}En$ to nY enable time	t_{en}	see Figure 7	$V_{CC} = 2.0V$	-	-	190 ns
			$V_{CC} = 4.5V$	-	-	38 ns
			$V_{CC} = 6.0V$	-	-	33 ns
$\overline{O}En$ to nY disable time	t_{dis}	see Figure 7	$V_{CC} = 2.0V$	-	-	190 ns
			$V_{CC} = 4.5V$	-	-	38 ns
			$V_{CC} = 6.0V$	-	-	33 ns
transition time	t_t	see Figure 6	$V_{CC} = 2.0V$	-	-	75 ns
			$V_{CC} = 4.5V$	-	-	15 ns
			$V_{CC} = 6.0V$	-	-	13 ns

Note:

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_{en} is the same as t_{PZL} and t_{PZH} .
- [3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [4] t_t is the same as t_{THL} and t_{TLH} .

Testing Circuit

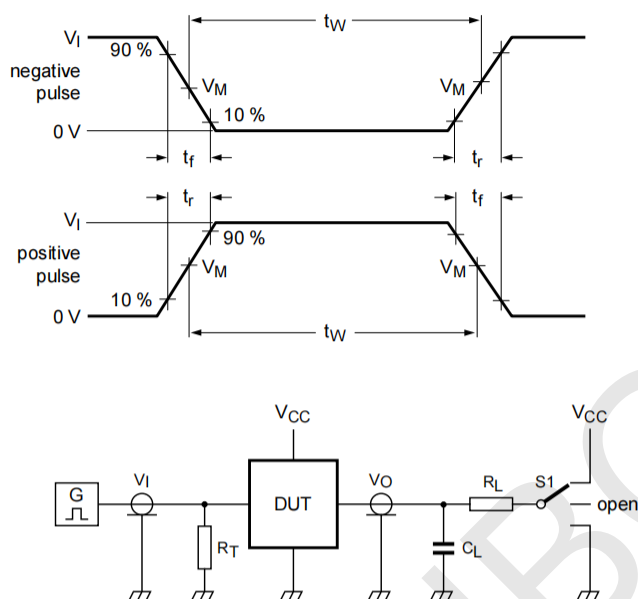


Figure 5. Test circuit for measuring switching times

Definitions for test circuit: R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

S1=Test selection switch.

AC Testing Waveforms

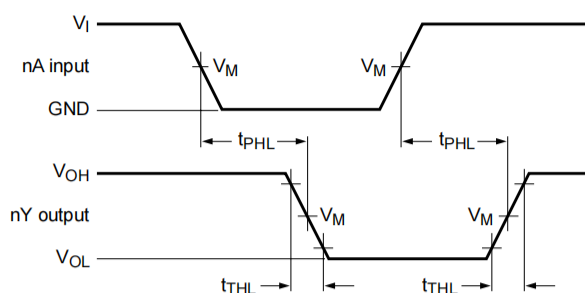


Figure 6. Input (nA) to output (nY) propagation delays and output transition times

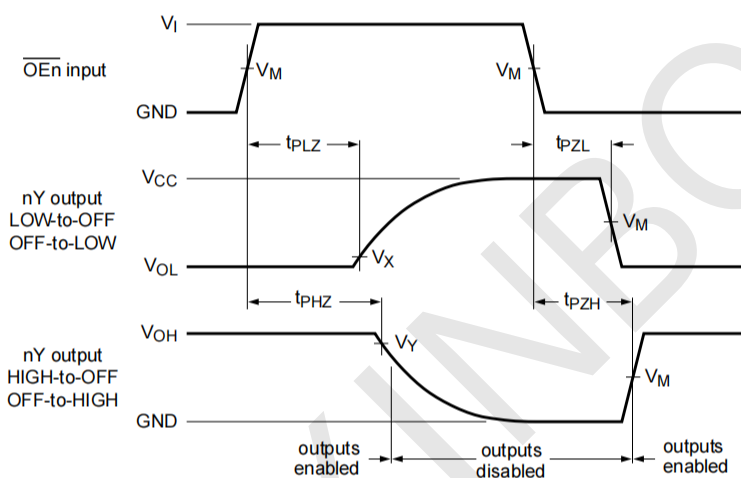


Figure 7. 3-state enable and disable times

Measurement Points

Type	Input	Output		
	V_M	V_M	V_X	V_Y
SN74LS365	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

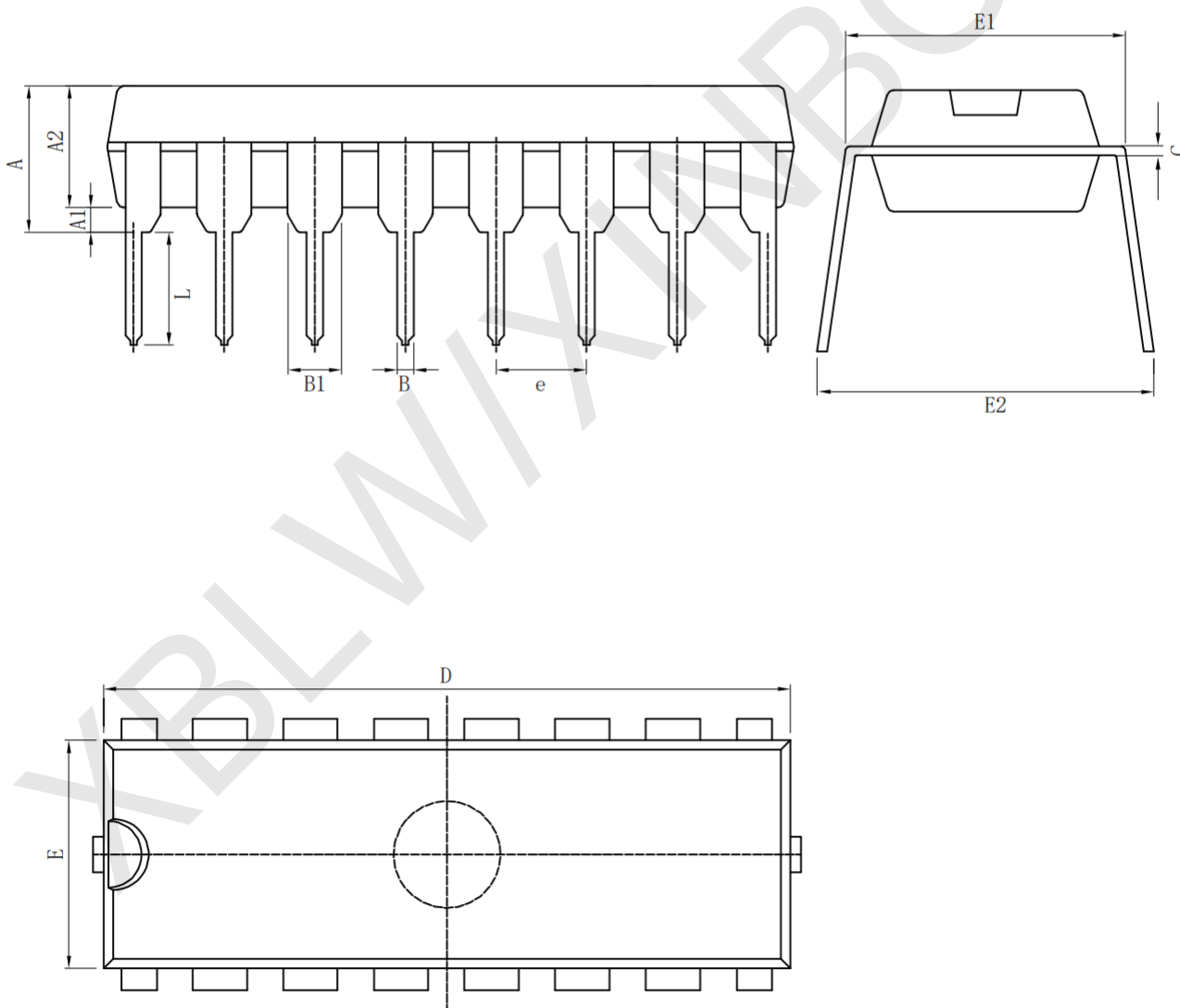
Test Data

Type	Input		Load		S1 position		
	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
SN74LS365	V_{CC}	6ns	15pF, 50pF	1k Ω	open	GND	V_{CC}

Package Information

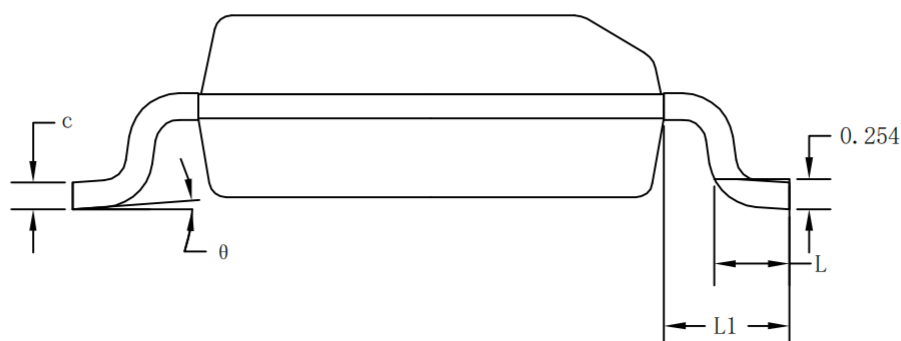
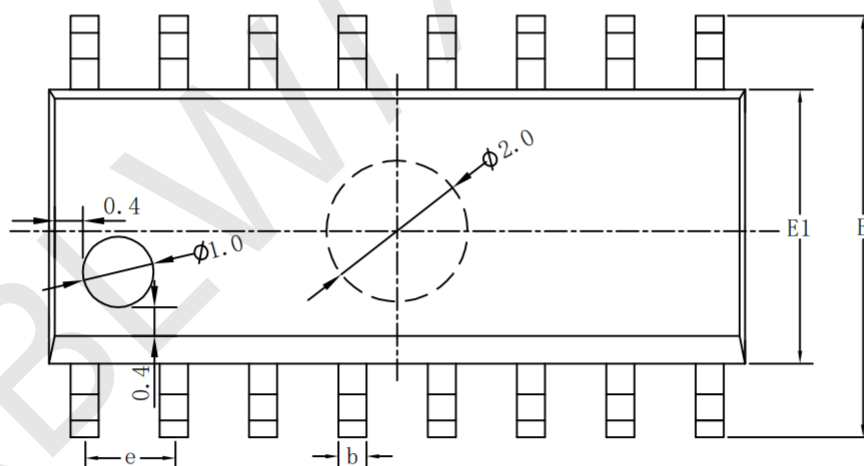
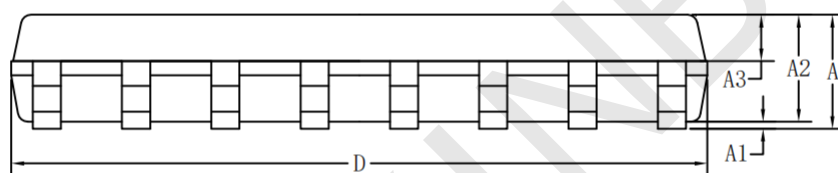
· DIP-16

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A	3.710	4.310	A	0.146	0.170
A1	0.510		A1	0.020	
A2	3.200	3.600	A2	0.126	0.142
B	0.380	0.570	B	0.015	0.022
B1	1.524 (BSC)		B1	0.060 (BSC)	
C	0.204	0.360	C	0.008	0.014
D	18.80	19.20	D	0.740	0.756
E	6.200	6.600	E	0.244	0.260
E1	7.320	7.920	E1	0.288	0.312
e	2.540 (BSC)		e	0.100 (BSC)	
L	3.000	3.600	L	0.118	0.142
E2	8.400	9.000	E2	0.331	0.354



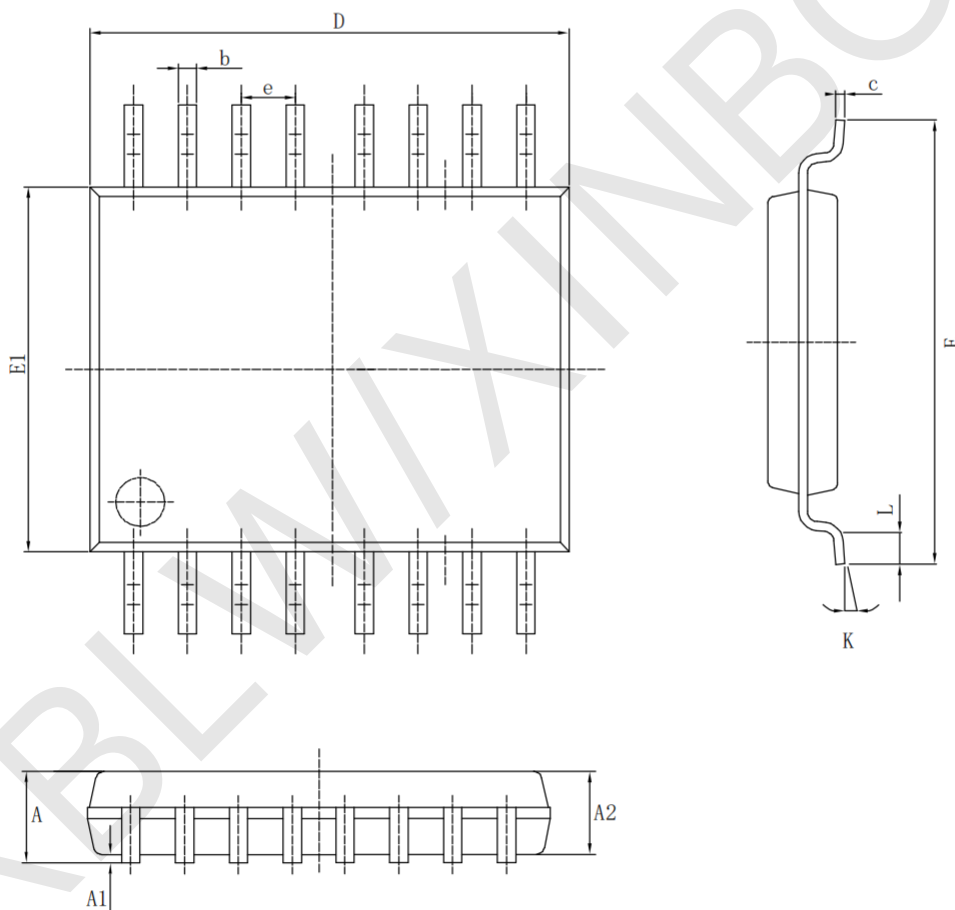
· SOP-16

Size Symbol	Dimensions In Millimeters			Size Symbol	Dimensions In Inches		
	Min (mm)	Nom (mm)	Max (mm)		Min (in)	Nom (in)	Max (in)
A	1.500	1.600	1.700	A	0.059	0.063	0.067
A1	0.100	0.150	0.250	A1	0.004	0.006	0.010
A2	1.400	1.450	1.500	A2	0.055	0.057	0.059
A3	0.600	0.650	0.700	A3	0.024	0.026	0.028
b	0.300	0.400	0.500	b	0.012	0.016	0.020
c	0.150	0.200	0.250	c	0.006	0.008	0.010
D	9.800	9.900	10.00	D	0.386	0.390	0.394
E	5.800	6.000	6.200	E	0.228	0.236	0.244
E1	3.850	3.900	3.950	E1	0.152	0.154	0.156
e	1.27 (BSC)			e	0.050 (BSC)		
L	0.500	0.600	0.700	L	0.020	0.024	0.028
L1	1.05 (BSC)			L1	0.041 (BSC)		
θ	0°	4°	8°	θ	0°	4°	8°



· TSSOP-16

Size Symbol	Dimensions In Millimeters		Size Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A		1.200	A		0.047
A1	0.050	0.150	A1	0.002	0.006
A2	0.800	1.050	A2	0.031	0.041
b	0.190	0.300	b	0.007	0.012
c	0.090	0.200	c	0.004	0.0089
D	4.900	5.100	D	0.193	0.201
E	6.200	6.600	E	0.244	0.260
E1	4.300	4.480	E1	0.169	0.176
e	0.65 (BSC)		e	0.0256 (BSC)	
K	0°	8°	K	0°	8°
L	0.450	0.750	L	0.018	0.030



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